<u>REMARKS</u>

In response to the Restriction Requirement mailed on August 3, 2001, Applicants hereby

elect Group II, claims 10-33, without transverse.

Claims 10-33 remain in the application. Independent claims 10, 21, and 23 have been

amended to more clearly define the present invention. These amendments are supported in the

specification at page 10, line 12 et seq. and FIGs. 5, 6a-c, 7, and 8.

An Information Disclosure Statement with a PTO-1449 is enclosed herewith. As no

action on the merits has been received, no fee is believed due for the Information Disclosure

Statement.

Please forward further communications to the address of record. If the Examiner needs to

contact the below-signed attorney to further the prosecution of the application, the contact

number is (503) 712-1682.

Respectfully submitted,

Dated: August 31, 2001

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VERSION OF CLAIMS WITH MARKINGS

IN THE CLAIMS:

1	10. (First Amended) A method of fabricating microelectronic dice, comprising:
2	providing a first encapsulated die assembly having an active surface and a back
3	surface, said first encapsulated die assembly including at least one first microelectronic
4	die having an active surface and at least one side and a first packaging material adjacent
5	said at least one first microelectronic die side, wherein said first packaging material
6	comprises a first microelectronic package core and a first encapsulation material, and
7	wherein said first encapsulation material comprises at least a portion of said first
8	encapsulation die assembly back surface; [and]
9	providing a second encapsulated die assembly having an active surface and a back
10	surface, said second encapsulated die assembly including at least one second
11	microelectronic die having an active surface and at least one side and a second packaging
12	material adjacent said at least one second microelectronic die side; and
13	attaching said first encapsulated die assembly back surface to said second
14	encapsulated assembly back surface.
1	21. (First Amended) The method of claim 10, wherein said providing a first
2	encapsulated die assembly comprises:
3	providing at least one first microelectronic die having an active surface
4	and at least one side;
5	abutting a protective film against said at least one first microelectronic die



6	active surface;
7	abutting said first microelectronic package core against said protective
8	film;
9	encapsulating said at least one microelectronic die with an encapsulation
10	material adjacent said at least one first microelectronic die side, wherein said
11	encapsulation material provides at least one surface of said encapsulation material
12	substantially planar to said first microelectronic die active surface; and
13	removing said protective film.
1	23. (First Amended) A method of fabricating a microelectronic package,
2	comprising:
3	forming a first encapsulated die assembly comprising:
4	providing at least one first microelectronic die having an active
5	surface and at least one side;
6	abutting a protective film against said at least one first
7	microelectronic die active surface;
8	abutting a first microelectronic package core against said protective
9	<u>film;</u> and
10	encapsulating said at least one microelectronic die with an
11	packaging material adjacent said at least one first microelectronic die side
12	to form a first encapsulated die active surface and a first encapsulated die
13	back surface;

14	forming a second encapsulated die assembly comprising:
15	providing at least one second microelectronic die having an active
16	surface and at least one side;
17	abutting a protective film against said at least one second
18	microelectronic die active surface; and
19	encapsulating said at least one microelectronic die with an
20	packaging material adjacent said at least one second microelectronic die
21	side to form a second encapsulated die active surface and a second
22	encapsulated die back surface; and
23	attaching said first encapsulated die assembly back surface to said second
24	encapsulated assembly back surface.